

18V, 2.5A Synchronous Step-Down DC/DC Converter

Description

The FR9204F is a synchronous step-down DC/DC converter with fast constant on time (FCOT) mode control. The device provides 4.5V to 18V input voltage range and 2.5A continuous load current capability. It is constant on time pulse width modulation (PWM) controller that supports FCOT mode control. Operation frequency depends on Input and output voltage condition.

The FR9204F fault protection includes cycle-by-cycle current limit, short circuit protection, UVLO and thermal shutdown. The soft-start function prevents inrush current at turn-on. The FR9204F use fast constant on time control that provides fast transient response, the noise immunity and all kinds of very low ESR output capacitor for ensuring performance stabilization.

The FR9204F is offered in SOT-563-6L package, which provides good thermal conductance.

Features

- Low R_{DS(ON)} Integrated Power MOSFET (80mΩ/40mΩ)
- Wide Input Voltage Range: 4.5V to 18V
- Output Voltage Range: 0.8V to 8V
- 2.5A Output Current
- FCOT Mode Enables Fast Transient Response
- Pseudo 500kHz Frequency
- Input Under Voltage Lockout
- Internal 1.5ms Soft-Start
- Cycle-by-Cycle Current Limit
- Hiccup Short Circuit Protection
- Over Temperature Protection with Auto Recovery
- SOT-563-6L Package

Applications

- STB (Set-Top-Box)
- LCD Display, TV
- Distributed Power System
- Networking, XDSL Modem

Pin Assignments

SD Package: SOT-563-6L

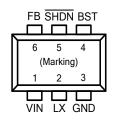
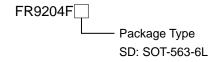


Figure 1. Pin Assignments of FR9204F

Ordering Information



SOT-563-6L Marking

Part Number	Product Code	
FR9204FSD	Av	



Typical Application Circuit

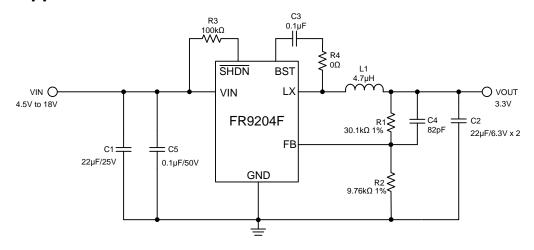


Figure 2. FR9204F Application Circuit

 V_{IN} =12V, the recommended BOM list is as below.

V _{OUT}	C1	R1	R2	C4	L1	C2
1.05V	22µF MLCC	4.87kΩ	16.2kΩ	68pF~220pF	1.5µH	22µF MLCC x2
1.2V	22µF MLCC	4.87kΩ	10kΩ	68pF~220pF	1.5µH	22µF MLCC x2
1.8V	22µF MLCC	4.87kΩ	3.92kΩ	68pF~220pF	2.2µH	22µF MLCC x2
2.5V	22µF MLCC	4.87kΩ	2.32kΩ	68pF~220pF	3.3µH	22µF MLCC x2
3.3V	22µF MLCC	30.1kΩ	9.76kΩ	68pF~220pF	4.7µH	22µF MLCC x2
5V	22µF MLCC	30.1kΩ	5.76kΩ	68pF~220pF	4.7µH	22µF MLCC x2

Table 1. FR9204F Recommended Component Values



Functional Pin Description

Pin Name	Pin No.	Pin Function
VIN	VIN 1 Power supply input pin. Placed input capacitors as close as possible from VIN to C influence.	
LX	2	Power switching node. Connect an external inductor to this switching node.
GND	3	Ground pin.
BST 4 High side gate drive boost pin. A capacitance between 100nF~1μF must be connected can boost the gate drive to fully turn on the internal high side NMOS.		High side gate drive boost pin. A capacitance between 100nF~1µF must be connected from this pin to LX. It can boost the gate drive to fully turn on the internal high side NMOS.
SHDN 5 Enable input pin. Pull high to turn on IC, and pull low to turn off IC. Connect VIN with a 100k self-startup.		Enable input pin. Pull high to turn on IC, and pull low to turn off IC. Connect VIN with a $100k\Omega$ resistor for self-startup.
FB	6	Voltage feedback input pin. Connect FB and VOUT with a resistive voltage divider. This IC senses feedback voltage via FB and regulates it at 0.8V.

Block Diagram

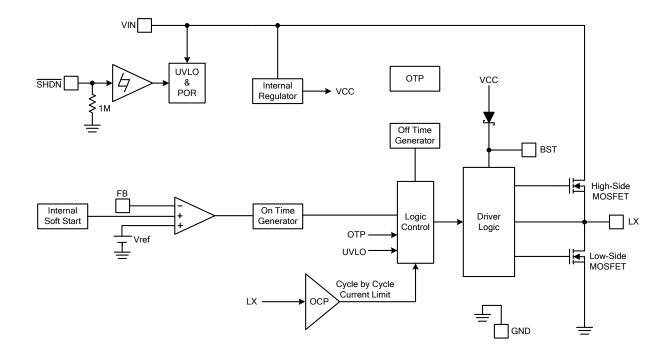


Figure 3. Block Diagram of FR9204F



Absolute Maximum Ratings (Note 1)

• Supply Voltage V _{IN}	-0.3V to +20V
• Enable Voltage V _{SHDN}	-0.3V to +20V
• LX Voltage V _{LX}	-0.3V to $(V_{IN} + 0.3V)$
Dynamic LX Voltage in 15ns Duration	-5V to V _{IN} +5V
• BST Pin Voltage V _{BST}	-0.3V to $(V_{LX}$ +6.5V)
All Other Pins Voltage	-0.3V to +6V
Maximum Junction Temperature (T _J)	+150°C
• Storage Temperature (T _S)	-65°C to +150°C
• Lead Temperature (Soldering, 10sec.)	+260°C
 Package Thermal Resistance, (θ_{JA}) (Note 2) 	
SOT-563-6L	130°C/W
 Package Thermal Resistance, (θ_{JC}) 	
SOT-563-6L	60°C/W

Note 1: Stresses beyond this listed under "Absolute Maximum Ratings" may cause permanent damage to the device. Note 2: θ_{JA} is measured at 25°C ambient with the component mounted on a high effective thermal conductivity 4-layer board of JEDEC-51-7. The thermal resistance greatly varies with layout, copper thickness, number of layers and PCB size.

Recommended Operating Conditions

(• Supply Voltage V _{IN}	+4.5V to +18V
•	Operating Ambient Temperature Range	-40°C to +85°C
	Operating Junction Temperature Range	-40°C to +125°C



Electrical Characteristics

(V_{IN}=12V, T_A=25°C, unless otherwise specified.)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
V _{IN} Quiescent Current	I _{DDQ}	V _{SHDN} =2V, V _{FB} =1V		0.3		mA
V _{IN} Shutdown Supply Current	I _{SD}	V _{SHDN} =0V		0.1	1	μΑ
Feedback Threshold Voltage	V_{FB}	4.5V≦V _{IN} ≦18V	0.788	0.8	0.812	V
Feedback Input Current	I _{FB}	V _{FB} =1V		0.01	0.1	μA
High-Side MOSFET R _{DS(ON)}	R _{DS(ON)}			80		mΩ
Low-Side MOSFET R _{DS(ON)}	R _{DS(ON)}			40		mΩ
Valley Current Limit (Note 3)	I _{LIMIT}		3.3	4	5.3	А
On Time (Note 3)	T _{ON}	V _{IN} =12V, V _{OUT} =1.05V		140		ns
Minimum Off Time	T _{OFF(MIN)}	V _{FB} =0.4V		200		ns
Input Supply Voltage UVLO Threshold	V _{UVLO(Vth)}	V _{IN} Rising	3.7	4	4.3	V
UVLO Threshold Hysteresis	V _{UVLO(HYS)}			0.25		V
Internal Soft-Start Period (Note 3)	T _{SS}			1.5		ms
SHDN Input Low Voltage	V _{SHDN(L)}				0.5	V
SHDN Input High Voltage	V _{SHDN(H)}		1.5			V
SHDN Input Current	I _{SHDN}	V _{SHDN} =2V		2		μΑ
Output Discharge Resistance (Note 3)	R _{DIS}			60		Ω
Thermal Shutdown Threshold (Note 3)	T _{SD}			160		°C
Thermal Shutdown Hysteresis (Note 3)	T _{HYS}			30		°C

Note 3: Not production tested.



Typical Performance Curves

V_{OUT}=1.05V

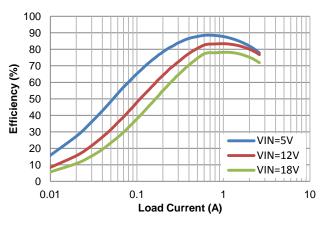


Figure 4. Efficiency vs. Load Current

V_{OUT}=3.3V

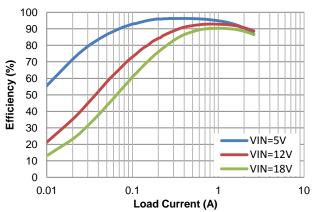


Figure 5. Efficiency vs. Load Current

V_{OUT}=5.0V

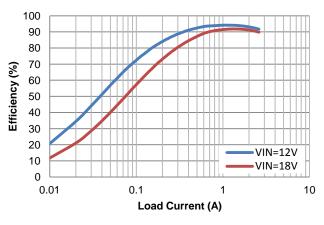


Figure 6. Efficiency vs. Load Current

$V_{IN}=12V$, $V_{OUT}=3.3V$, $I_{OUT}=0A\sim2.5A$

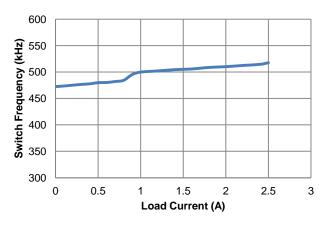


Figure 7. Switch Frequency vs. Load Current

V_{SHDN}=2V, V_{FB}=1V

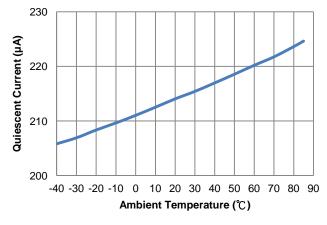


Figure 8. Quiescent Current vs. Ambient Temperature

$V_{IN}=12V$

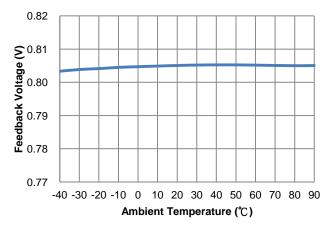


Figure 9. Feedback Voltage vs. Ambient Temperature



Typical Performance Curves (Continued)

 $V_{IN}=12V$, $V_{OUT}=3.3V$, $C1=22\mu Fx1$, $C2=22\mu Fx2$, C4=82pFx1, $L1=4.7\mu H$, $TA=+25^{\circ}C$, unless otherwise noted.

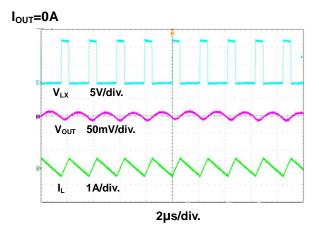


Figure 10. Steady State Waveform

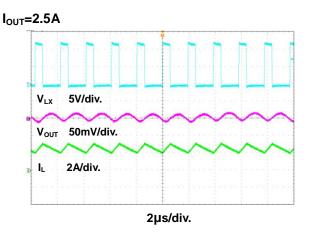


Figure 11. Steady State Waveform

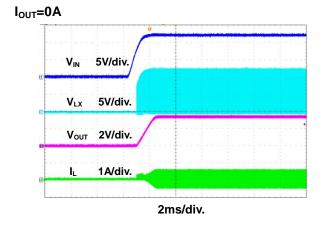


Figure 12. Power On Through VIN Waveform

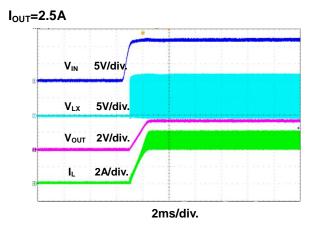


Figure 13. Power On Through VIN Waveform

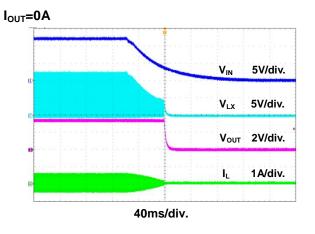


Figure 14. Power Off Through VIN Waveform

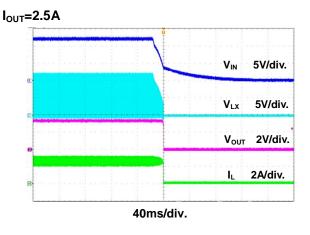


Figure 15. Power Off Through VIN Waveform



Typical Performance Curves (Continued)

 V_{IN} =12V, V_{OUT} =3.3V, C1=22 μ Fx1, C2=22 μ Fx2, C4=82 μ Fx1, L1=4.7 μ H, TA=+25°C, unless otherwise noted.

I_{OUT}=0A

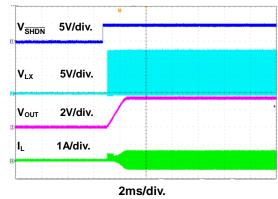


Figure 16. Power On Through SHDN Waveform

I_{OUT}=2.5A

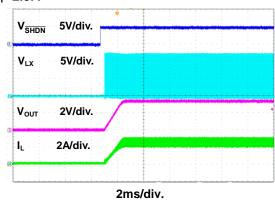


Figure 17. Power On Through SHDN Waveform

$I_{OUT}=0A$

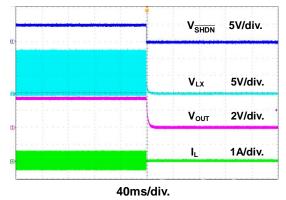


Figure 18. Power Off Through SHDN Waveform

I_{OUT}=2.5A

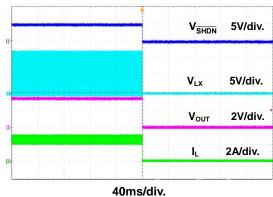


Figure 19. Power Off Through SHDN Waveform

I_{OUT}=1.25A to 2.5A

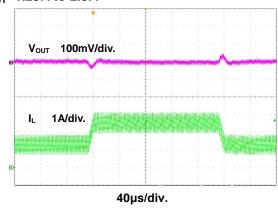


Figure 20. Load Transient Waveform



Function Description

The FR9204F is a synchronous step-down DC/DC converter with fast constant on time (FCOT) mode control. It has integrated high-side ($80m\Omega$, typ) and low-side ($40m\Omega$, typ) power switches, and provides 2.5A continuous load current. It regulates input voltage from 4.5V to 18V, and down to an output voltage as low as 0.8V. Using FCOT control scheme provides fast transient response, which can minimize the component size without additional external compensation network.

Enable

The FR9204F \overline{SHDN} pin provides digital control to turn on/turn off the regulator. When the voltage of \overline{SHDN} exceeds the threshold voltage, the regulator starts the soft start function. If the \overline{SHDN} pin voltage is below than the shutdown threshold voltage, the regulator will turn into the shutdown mode and the shutdown current will be smaller than 1µA. For auto start-up operation, connect \overline{SHDN} to VIN through a $100k\Omega$ resistor.

Soft Start

The FR9204F employs internal soft start function to reduce input inrush current during start up. The typical value of internal soft start time is 1.5ms.

Input Under Voltage Lockout

When the FR9204F is power on, the internal circuits are held inactive until V_{IN} voltage exceeds the input UVLO threshold voltage. And the regulator will be disabled when V_{IN} is below the input UVLO threshold voltage. The hysteretic of the UVLO comparator is 250mV (typ).

Over Current Protection

The FR9204F over current protection function is implemented using cycle-by-cycle current limit architecture. The inductor current is monitored by Low-side MOSFET. When the load current increases, the inductor current also increases. When the valley inductor current reaches the current limit threshold, the output voltage starts to drop. When the over current condition is removed, the output voltage returns to the regulated value.

Short Circuit Protection

The FR9204F provides short circuit protection function to prevent the device damage from short condition. When the short condition occurs and the feedback voltage drops lower than 0.33V, the oscillator frequency will be reduced naturally and hiccup mode will be triggered to prevent the inductor current increasing beyond the current limit. Once the short condition is removed, the frequency will return to normal.

Over Temperature Protection

The FR9204F incorporates an over temperature protection circuit to protect itself from overheating. When the junction temperature exceeds the thermal shutdown threshold temperature, the regulator will be shutdown. And the hysteretic of the over temperature protection is 30°C (typ).

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Application Information

Output Voltage Setting

The output voltage V_{OUT} is set using a resistive divider from the output to FB. The FB pin regulated voltage is 0.8V. Thus the output voltage equation is:

$$V_{OUT} = 0.8V \times \left(1 + \frac{R1}{R2}\right)$$

Table 2 lists recommended values of R1 and R2 for most used output voltage.

Table 2 Recommended Resistance Values

V _{out}	R1	R2
5V	30.1kΩ	5.76kΩ
3.3V	30.1kΩ	9.76kΩ
2.5V	4.87kΩ	2.32kΩ
1.8V	4.87kΩ	3.92kΩ
1.2V	4.87kΩ	10kΩ
1.05V	4.87kΩ	16.2kΩ

Place resistors R1 and R2 close to FB pin to prevent stray pickup.

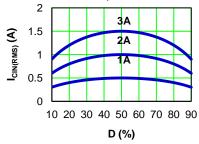
Input Capacitor Selection

The use of the input capacitor is filtering the input voltage ripple and the MOSFETS switching spike voltage. Because the input current to the step-down converter is discontinuous, the input capacitor is required to supply the current to the converter to keep the DC input voltage. The capacitor voltage rating should be 1.25 to 1.5 times greater than the maximum input voltage. The input capacitor ripple current RMS value is calculated as:

$$I_{CIN(RMS)} = I_{OUT} \times \sqrt{D \times (1-D)}$$

$$D = \frac{V_{OUT}}{V_{IN}}$$

Where D is the duty cycle of the power MOSFET. This function reaches the maximum value at D=0.5 and the equivalent RMS current is equal to $I_{OUT}/2$. The following diagram is the graphical representation of above equation.



A low ESR capacitor is required to keep the noise minimum. Ceramic capacitors are better, but tantalum or low ESR electrolytic capacitors may also suffice. When using tantalum or electrolytic capacitors, a $0.1\mu F$ ceramic capacitor should be placed as close to the IC as possible.

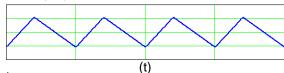
Output Capacitor Selection

The output capacitor is used to keep the DC output voltage and supply the load transient current. When operating in constant current mode, the output ripple is determined by four components:

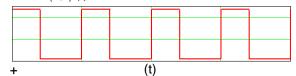
$$V_{RIPPLE}(t) = V_{RIPPLE(C)}(t) + V_{RIPPLE(ESR)}(t) + V_{RIPPLE(ESL)}(t) + V_{NOISE}(t)$$

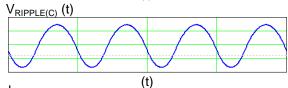
The following figures show the form of the ripple contributions.

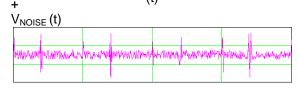
$V_{RIPPLE(ESR)}(t)$

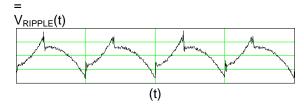


V_{RIPPLE(ESL)} (t)











Application Information (Continued)

$$V_{RIPPLE(ESR)} = \frac{V_{OUT}}{F_{OSC} \times L} \times \left(1 - \frac{V_{OUT}}{V_{IN}}\right) \times ESR$$

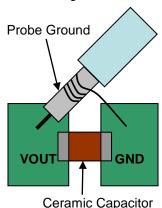
$$V_{RIPPLE(ESL)} = \frac{ESL}{L} \times V_{IN}$$

$$V_{RIPPLE(C)} = \frac{V_{OUT}}{8 \times F_{OSC^2} \times L \times C_{OUT}} \times \left(1 - \frac{V_{OUT}}{V_{IN}}\right)$$

Where F_{OSC} is the switching frequency, L is the inductance value, V_{IN} is the input voltage, ESR is the equivalent series resistance value of the output capacitor, ESL is the equivalent series inductance value of the output capacitor and the C_{OUT} is the output capacitor.

Low ESR capacitors are preferred to use. Ceramic, tantalum or low ESR electrolytic capacitors can be used depending on the output ripple requirement. When using the ceramic capacitors, the ESL component is usually negligible.

It is important to use the proper method to eliminate high frequency noise when measuring the output ripple. The figure shows how to locate the probe across the capacitor when measuring output ripple. Removing the scope probe plastic jacket in order to expose the ground at the tip of the probe. It gives a very short connection from the probe ground to the capacitor and eliminating noise.



Inductor Selection

The output inductor is used for storing energy and filtering output ripple current. But the trade-off condition often happens between maximum energy storage and the physical size of the inductor. The first consideration for selecting the output inductor is to make sure that the inductance is large enough to keep the converter in the continuous current mode.

That will lower ripple current and result in lower output ripple voltage. The ΔI_L is inductor peak-to-peak ripple current:

$$\Delta I_{L} = \frac{V_{OUT}}{F_{OSC} \times L} \times \left(1 - \frac{V_{OUT}}{V_{IN}}\right)$$

A good compromise value between size and efficiency is to set the peak-to-peak inductor ripple current ΔI_L equal to 30% of the maximum load current. But setting the peak-to-peak inductor ripple current ΔI_L between 20%~50% of the maximum load current is also acceptable. Then the inductance can be calculated with the following equation:

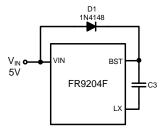
$$\Delta I_L = 0.3 \times I_{OUT(MAX)}$$

$$L = \frac{(V_{IN} - V_{OUT}) \times V_{OUT}}{V_{IN} \times F_{OSC} \times \Delta I_{L}}$$

To guarantee the required output current, the inductor needs a saturation current rating and a thermal rating that exceeds IL (peak current). These are minimum requirements. To maintain control of inductor current in overload and short circuit conditions, some applications may desire current ratings up to the current limit value.

External Diode Selection

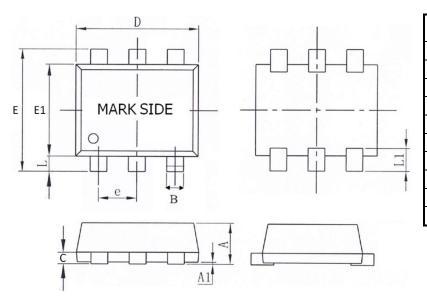
For 5V input applications, it is recommended to add an external boost diode. This helps improving the efficiency. The boost diode can be a low cost one such as 1N4148.





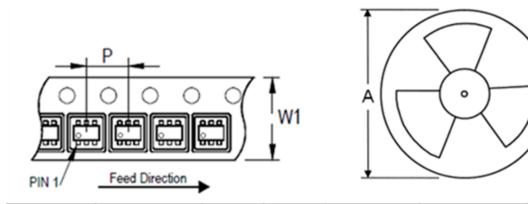
Outline Information

SOT-563-6L Package (Unit: mm)



SYMBOLS	DIMENSION IN MILLIMETER					
UNIT	MIN	MAX				
Α	0.525	0.600				
A1	0.000	0.050				
В	0.170	0.270				
С	0.110	0.160				
D	1.500	1.700				
Е	1.500	1.700				
E1	1.100	1.300				
е	0.500 BSC					
L	0.100	0.300				
L1	0.200	0.400				

Carrier Dimensions



Tape Size	Pocket Pitch	Reel Size (A)		Reel Width	Empty Cavity	Units per Reel
(W1) mm	(P) mm	in mm		(W2) mm	Length mm	
8	4	7	180	8.4	300~1000	5,000